Configurable Multiple–Function Gate

HITACHI

ADE-205-717 (Z)

Rev.0 Feb. 2003

Description

The HD74LV1GW57A has configurable multiple–function gate in a 6 pin package. The Output state is determined by eight patterns of 3–bit input. The user can choose the logic functions AND, NAND, NOR, EX–NOR. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

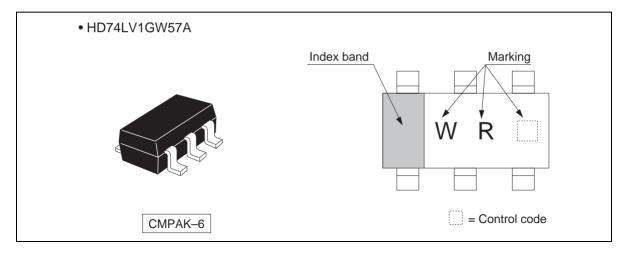
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Supply voltage range : 1.65 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current $\pm 6 \text{ mA}$ (@V_{CC} = 3.0 V to 3.6 V), $\pm 12 \text{ mA}$ (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1GW57ACME	CMPAK-6 pin	CMPAK-6V(O)	СМ	E (3,000 pcs / Reel)



Outline and Article Indication



Function Table

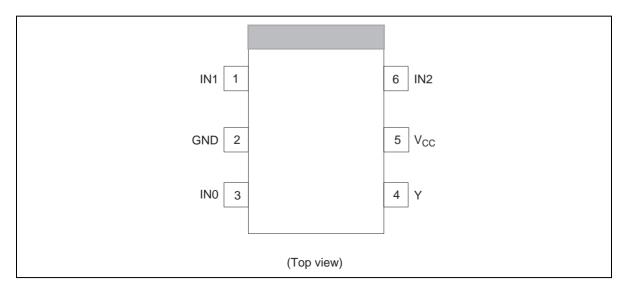
Inputs			Output	
IN2	IN1	INO	Y	
L	L	L	Н	
L	L	Н	L	
L	Н	L	Н	
L	Н	Н	L	
Н	L	L	L	
Н	L	Н	L	
Н	Н	L	Н	
Н	Н	Н	Н	

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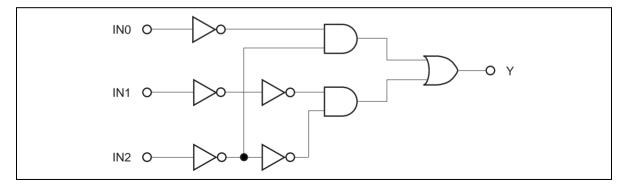
H : High level

L : Low level

Pin Arrangement



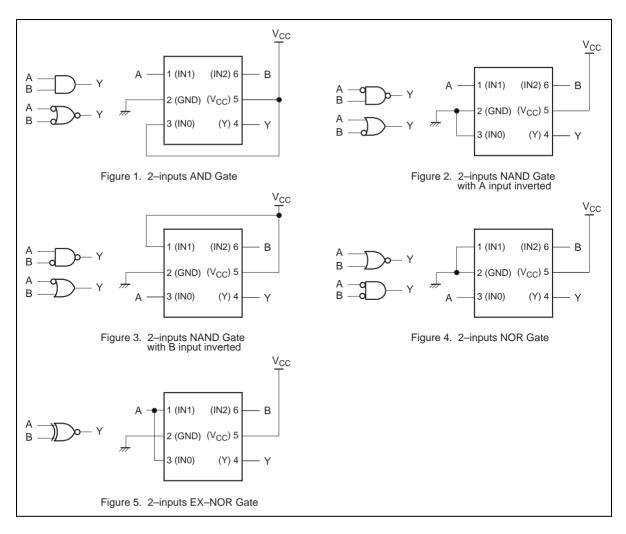
Logic Diagram



Function Selection Table

Logic Function	Figure No.	
2–input AND	1	
2-input AND with both inputs inverted	4	
2-input NAND with one input inverted	2, 3	
2-input OR with one input inverted	2, 3	
2-input NOR	4	
2-input NOR with both inputs inverted	1	
2-input EX-NOR	5	

Logic Configurations



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input voltage range *1	VI	-0.5 to 7.0	V	
Output voltage range *1, 2	Vo	-0.5 to V _{CC} + 0.5	V	Output : H or L
		-0.5 to 7.0		V _{CC} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	l _{ок}	±50	mA	$V_0 < 0 \text{ or } V_0 > V_{CC}$
Continuous output current	lo	±25	mA	$V_0 = 0$ to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 5.5 V maximum.

3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	Vcc	V	
Output current	I _{OL}	_	1	mA	V_{CC} = 1.65 to 1.95 V
		—	2		V_{CC} = 2.3 to 2.7 V
		_	6		V_{CC} = 3.0 to 3.6 V
		_	12		V_{CC} = 4.5 to 5.5 V
	I _{OH}	—	-1		V _{CC} = 1.65 to 1.95 V
		—	-2		V_{CC} = 2.3 to 2.7 V
		_	-6		V_{CC} = 3.0 to 3.6 V
		—	-12		V_{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	300	ns / V	V _{CC} = 1.65 to 1.95 V
		0	200		V_{CC} = 2.3 to 2.7 V
		0	100		V_{CC} = 3.0 to 3.6 V
		0	20		V_{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	-40	85	°C	

Recommended Operating Conditions

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

• Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{cc} (V) *	Min	Тур	Max	Unit	Test condition
Threshold	V_{T}^{+}	1.65 to 1.95	_	_	V _{CC} ×0.75	V	
voltage		2.5	_	_	1.75	_	
		3.3	_	_	2.31	_	
		5.0	_	_	3.50	-	
	V _T ⁻	1.65 to 1.95	V _{CC} ×0.25	_	—	_	
		2.5	0.75	_	—	_	
		3.3	0.99	_		_	
		5.0	1.5	_	—	_	
	ΔV_T	1.65 to 1.95	0.1	_	V _{CC} ×0.4	_	
		2.5	0.25	_	1.0	_	
		3.3	0.33	_	1.32	_	
		5.0	0.5	_	2.0	_	
Output voltage	V _{OH}	Min to Max	V _{cc} -0.1	_		V	I _{OH} = -50 μA
		1.65	1.4	_	—	_	I _{OH} = -1 mA
		2.3	2.0	_	—	_	$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	—	_	I _{OH} =6 mА
		4.5	3.8	_	_	-	I _{OH} = -12 mA
	V _{OL}	Min to Max	_	_	0.1	_	I _{OL} = 50 μA
		1.65	_	_	0.3	_	I _{OL} = 1 mA
		2.3	_	_	0.4	_	I _{OL} = 2 mA
		3.0	_	_	0.44	-	I _{OL} = 6 mA
		4.5	_	_	0.55	_	I _{OL} = 12 mA
Input current	l _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I _{CC}	5.5	_	_	10	μA	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
Output leakage current	I _{OFF}	0	—	_	5	μA	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	CIN	3.3	_	3.0		pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 1.8 \pm 0.15 \text{ V}$

ltem	Symbol	Ta = 2	25°C		Ta = −40 to 85°C		Unit		FROM	то
		Min	Тур	Max	Min	Max	-	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	15.8	29.4	1.0	33.0	ns	$C_L = 15 \text{ pF}$	IN	Υ
delay time	t _{PHL}	_	22.6	40.9	1.0	45.0	-	$C_L = 50 \text{ pF}$	_	

• $V_{CC} = 2.5 \pm 0.2 \text{ V}$

ltem	Symbol	Ta = 2	25°C		Ta = −40 to 85°C		Unit		FROM	то
		Min	Тур	Мах	Min	Max	-	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	9.4	17.6	1.0	21.0	ns	$C_L = 15 \text{ pF}$	IN	Υ
delay time	t _{PHL}	_	12.6	22.6	1.0	26.5	_	$C_L = 50 \text{ pF}$	_	

• $V_{CC} = 3.3 \pm 0.3 V$

Item	Symbol	Ta = 2	25°C		Ta = −40 to 85°C		Unit		FROM	то
		Min	Тур	Max	Min	Max	-	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	7.0	11.0	1.0	13.0	ns	$C_L = 15 \text{ pF}$	IN	Y
delay time	t _{PHL}	—	9.5	14.5	1.0	16.5	_	$C_L = 50 \text{ pF}$	_	

• $V_{CC} = 5.0 \pm 0.5 V$

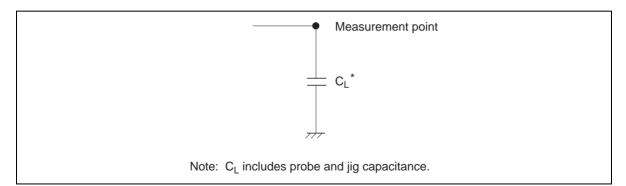
ltem	Symbol	Ta = 2	25°C		Ta = -40 to 85°C		Unit		FROM	то
		Min	Тур	Max	Min	Max	-	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	4.8	6.8	1.0	8.0	ns	$C_L = 15 \text{ pF}$	IN	Y
delay time	t _{PHL}	_	6.3	8.8	1.0	10.0	_	$C_L = 50 \text{ pF}$	_	

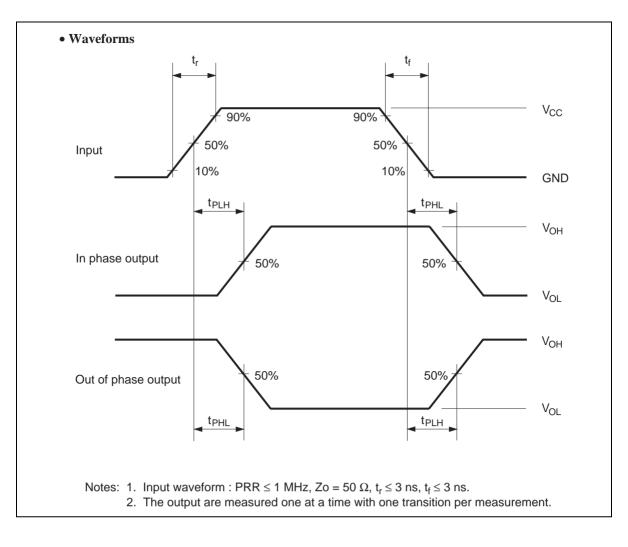
Operating Characteristics

• $C_L = 50 \text{ pF}$

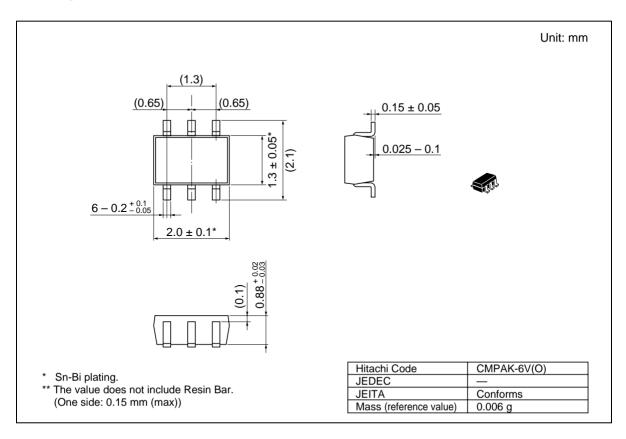
ltem	Symbol	V _{cc} (V)	Ta = 25	°C		Unit	Test Conditions		
			Min	Тур	Max				
Power dissipation	C _{PD}	3.3	_	8.5	_	pF	f = 10 MHz		
capacitance		5.0		10.0	—	_			

Test Circuit





Package Dimensions



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